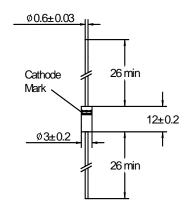
FAST RECOVERY HIGH VOLTAGE DIODES

Features

- Supersmall size.
- High reliability.
- High speed switching.

Applications

- Rectification for high voltage power supply of color T.V.
- Rectification for high voltage power supply of CRT display.
- Rectification for high voltage power supply of others.



Dimensions in mm

Absolute Maximum Ratings

	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	16	KV
Non-Repetitive Peak Reverse Voltage	V_{RSM}	20	KV
Average Forward Current 50Hz Half-sine wave, Resistance load, T _a =25°C	I _{F(AV)}	5	mA
Surge(Non-Repetitive) Forward Current 50Hz Half-sine wave, 1/2cycle, T _a =25°C	I _{FSM}	0.5	А
Operating Ambient Temperature	Ta	-40 to 100	°C
Storage Temperature	T _{stg}	-40 to 120	°C
Virtual Junction Temperature	T _(vj)	120	°C

Characteristics (T_a=25 °C unless otherwise specified)

		Symbol	Min.	Тур.	Max.	Unit
Forward Voltage at I _F =10mA		V _F	1	1	60	V
Reverse Current at V _R =V _{RRM}	T _a =25 °C	I _R	ı	1	2	μA
	T _a =100 °C		-	-	5	μA
Reverse Recovery Time at I _F =2mA, I _R =4mA		t _{rr}	1	-	0.08	μs



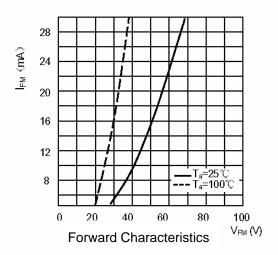


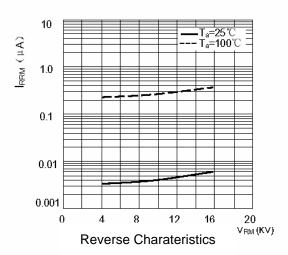


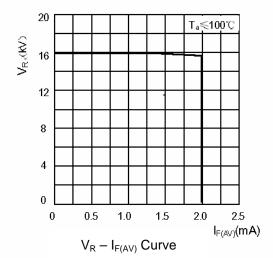


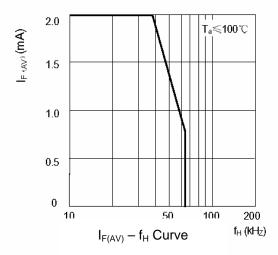
SEMTECH ELECTRONICS LTD.

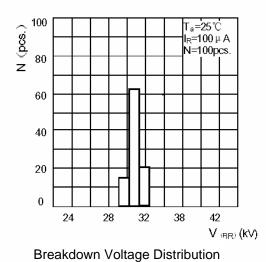
Characteristics(Typical)

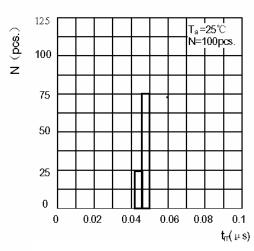












Reverse Recovery Time Distribution









Dated: 20/09/2005